Notice of Allowability	Application No.	pplication No. Applicant(s)		
	10/781,761	LEE ET AL.		
	Examiner	Art Unit	1 (	
	Chandra Chaudhari	2891		
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this apport or other appropriate communication GHTS. This application is subject to	plication. If not include will be mailed in due	ded e course. <b>THIS</b>	
1. This communication is responsive to <i>February 20, 2004</i> .				
2. The allowed claim(s) is/are <u>1-35</u> .				
<ul> <li>3.</li></ul>	been received.  been received in Application No cuments have been received in this  of this communication to file a reply ENT of this application.  itted. Note the attached EXAMINER as reason(s) why the oath or declara t be submitted. on's Patent Drawing Review ( PTO- as Amendment / Comment or in the Comment or in the Comment of the drawing he header according to 37 CFR 1.121(comment of BIOLOGICAL MATERIAL In	national stage applicational stage application of the front (not the d).	equirements  NOTICE OF	
Attachment(s)  1. ☑ Notice of References Cited (PTO-892)  2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)  3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 8-4-05, 9-28-04, 7-29-0  4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material	5. ☐ Notice of Informal P 6. ☐ Interview Summary Paper No./Mail Dat 8), 7. ☐ Examiner's Amenda 8. ☑ Examiner's Stateme 9. ☐ Other	(PTO-413), te nent/Comment	·	

Application/Control Number: 10/781,761

Art Unit: 2891

The following is an examiner's statement of reasons for allowance:

The prior art does not disclose to form first conductive spacers on inner walls of the trench, and separating the ONO dielectric layer into two portions by selectively removing the exposed portion of the ONO dielectric layer using the first conductive spacers as an etch mask as claimed.

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Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Chandra Chaudhari whose telephone number is 571-272-1688. The examiner can normally be reached on Mon - Fri (9:00-5:30).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Bill Baumeister can be reached on 571-272-1722. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Chandra Chaudhari Primary Examiner Art Unit 2891

Chandra Chaudhari August 30, 2005

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